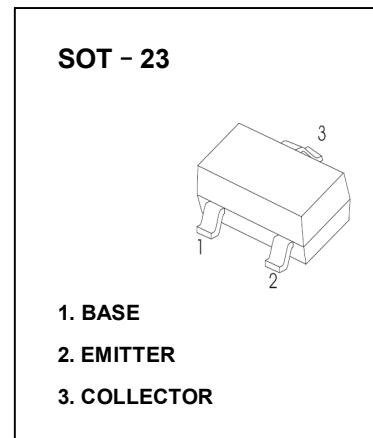


SOT-23 Plastic-Encapsulate Transistors**MMBTA44 TRANSISTOR (NPN)****FEATURES**

- High Collector-Emitter Voltage
- Complement to MMBTA94

**MARKING: 3D****MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{\text{CBO}}$	Collector-Base Voltage	500	V
$V_{\text{CEO}}$	Collector-Emitter Voltage	400	V
$V_{\text{EBO}}$	Emitter-Base Voltage	6	V
$I_c$	Collector Current	100	mA
$P_c$	Collector Power Dissipation	350	mW
$R_{\text{QJA}}$	Thermal Resistance From Junction To Ambient	357	°C/W
$T_j$	Junction Temperature	150	°C
$T_{\text{stg}}$	Storage Temperature	-55~+150	°C

**ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_c=100\mu\text{A}, I_E=0$	500			V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}^*$	$I_c=1\text{mA}, I_B=0$	400			V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_E=10\mu\text{A}, I_C=0$	6			V
Collector cut-off current	$I_{\text{CBO}}$	$V_{\text{CB}}=400\text{V}, I_E=0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{\text{EBO}}$	$V_{\text{EB}}=4\text{V}, I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE(1)}^*$	$V_{CE}=10\text{V}, I_c=1\text{mA}$	40			
	$h_{FE(2)}^*$	$V_{CE}=10\text{V}, I_c=10\text{mA}$	50		200	
	$h_{FE(3)}^*$	$V_{CE}=10\text{V}, I_c=50\text{mA}$	45			
	$h_{FE(4)}^*$	$V_{CE}=10\text{V}, I_c=100\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(\text{sat})1}^*$	$I_c=1\text{mA}, I_B=0.1\text{mA}$			0.4	V
	$V_{CE(\text{sat})2}^*$	$I_c=10\text{mA}, I_B=1\text{mA}$			0.5	V
	$V_{CE(\text{sat})3}^*$	$I_c=50\text{mA}, I_B=5\text{mA}$			0.75	V
Base-emitter saturation voltage	$V_{BE(\text{sat})}^*$	$I_c=10\text{mA}, I_B=1\text{mA}$			0.75	V
Collector output capacitance	$C_{\text{ob}}$	$V_{\text{CB}}=20\text{V}, I_E=0, f=1\text{MHz}$			7	pF
Emitter input capacitance	$C_{\text{ib}}$	$V_{\text{EB}}=0.5\text{V}, I_C=0, f=1\text{MHz}$			130	pF

\*Pulse test: pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2.0\%$ .